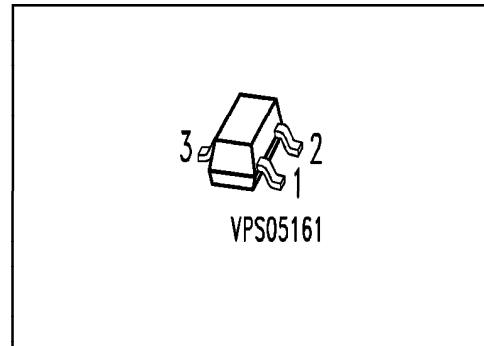


Preliminary Data

- For UHF/VHF frequency converters and local oscillators.
- $f_T = 2.2$ GHz



ESD: Electrostatic discharge sensitive device, observe handling precautions!

Type	Marking	Ordering Code (tape and reel)	Pin Configuration			Package ¹⁾
			1	2	3	
BF 777	LFs	Q62702-F1426	B	E	C	SOT-23

Maximum Ratings

Parameter	Symbol	Values	Unit
Collector-emitter voltage	V_{CEO}	20	V
Collector-emitter voltage, $V_{BE} = 0$	V_{CES}	25	
Collector-base voltage	V_{CBO}	30	
Emitter-base voltage	V_{EBO}	3	
Collector current	I_C	50	mA
Peak collector current, $f \geq 10$ MHz	I_{CM}	50	
Base current	I_B	8	
Peak base current, $f \geq 10$ MHz	I_{BM}	10	
Total power dissipation, $T_S \leq 97$ °C ³⁾	P_{tot}	150	mW
Junction temperature	T_j	150	°C
Ambient temperature range	T_A	- 65 ... + 150	
Storage temperature range	T_{stg}	- 65 ... + 150	

Thermal Resistance

Junction - ambient ²⁾	$R_{th JA}$	≤ 430	K/W
Junction - soldering point ³⁾	$R_{th JS}$	≤ 350	

¹⁾ For detailed information see chapter Package Outlines.

²⁾ Package mounted on alumina 15 mm × 16.7 mm × 0.7 mm.

³⁾ T_S is measured on the collector lead at the soldering point to the pcb.

Electrical Characteristicsat $T_A = 25^\circ\text{C}$, unless otherwise specified.

Parameter	Symbol	Values			Unit
		min.	typ.	max.	

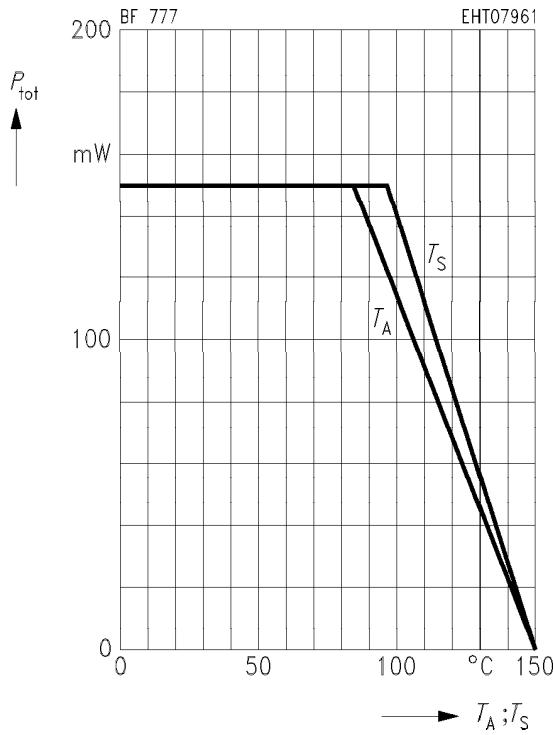
DC Characteristics

Collector-emitter breakdown voltage $I_C = 1 \text{ mA}, I_B = 0$	$V_{(\text{BR})\text{CE}0}$	20	—	—	V
Collector-emitter cutoff current $V_{\text{CE}} = 15 \text{ V}, V_{\text{BE}} = 0$	I_{CES}	—	—	1	μA
Collector-base cutoff current $V_{\text{CB}} = 30 \text{ V}, I_E = 0$ $V_{\text{CB}} = 15 \text{ V}, I_E = 0$	I_{CBO}	—	—	1.0	
Emitter-base cutoff current $V_{\text{EB}} = 3 \text{ V}, I_C = 0$	I_{EBO}	—	—	0.5	
DC current gain $I_C = 5 \text{ mA}, V_{\text{CE}} = 10 \text{ V}$	h_{FE}	30	—	200	—
Collector-emitter saturation voltage $I_C = 10 \text{ mA}, I_B = 5 \text{ mA}$ $I_C = 10 \text{ mA}, I_B = 1 \text{ mA}$	V_{CEsat}	—	—	0.7	V
		—	0.1	0.4	

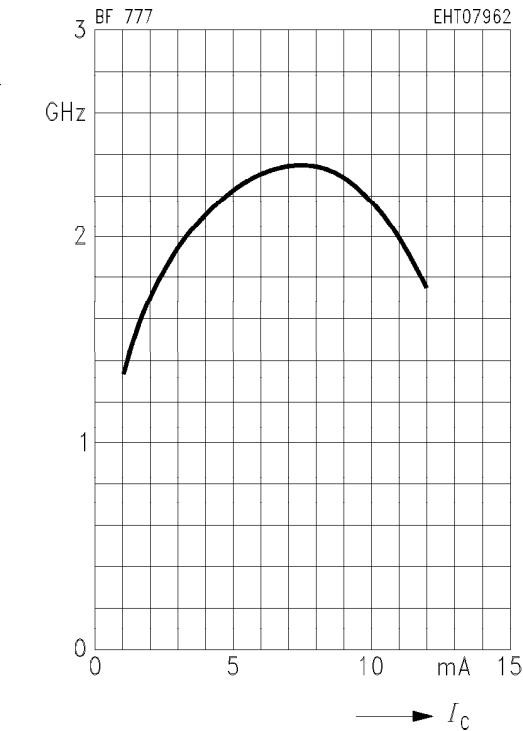
AC Characteristics

Transition frequency $I_C = 5 \text{ mA}, V_{\text{CE}} = 10 \text{ V}, f = 200 \text{ MHz}$	f_T	1.4	2.2	—	GHz
Collector-base capacitance $V_{\text{CB}} = 10 \text{ V}, V_{\text{BE}} = v_{\text{be}} = 0, f = 1 \text{ MHz}$	C_{cb}	—	0.5	0.85	pF
Collector-emitter capacitance $V_{\text{CE}} = 10 \text{ V}, V_{\text{BE}} = v_{\text{be}} = 0, f = 1 \text{ MHz}$	C_{ce}	—	0.33	—	

Total power dissipation $P_{\text{tot}} = f(T_A^*; T_S)$
 *Package mounted on alumina



Transition frequency $f_T = f(I_C)$
 $V_{CE} = 10 \text{ V}, f = 200 \text{ MHz}$



Collector-base capacitance $C_{cb} = f(V_{CB})$
 $V_{BE} = v_{be} = 0, f = 1 \text{ MHz}$

